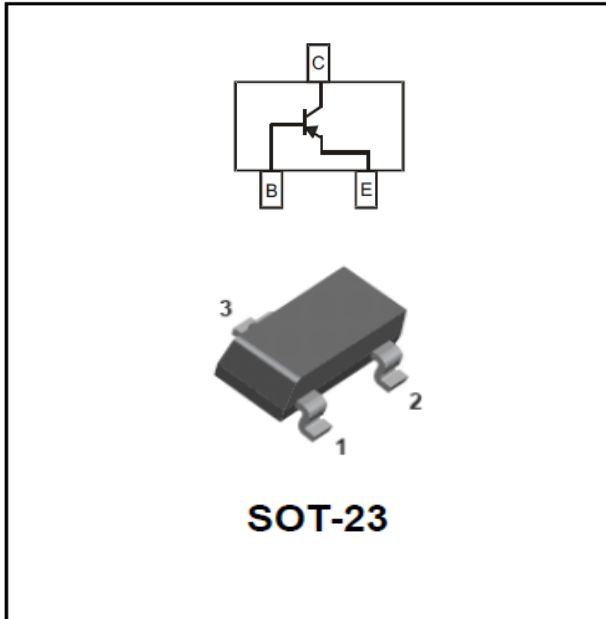


PNP General Purpose Amplifier



Features

- Low collector-emitter saturation voltage
- High current capability
- Epoxy meets UL-94 V-0 flammability rating
- Halogen free available upon request by adding suffix "HF"
- Moisture Sensitivity Level 1
- Marking:3E

Applications

- Supply line switching circuits
- Battery management
- DC-DC convertor
- Strobe flash
- Motor and lamp driver

■ Maximum Ratings (Ta=25°C)

Item	Symbol	Unit	Conditions	Value
Collector-Emitter Voltage*	V_{CE0}	V	$I_C = -1\text{mA}$, $I_B = 0$	-30
Collector-Base Voltage	V_{CBO}	V	$I_C = -100\mu\text{A}$, $I_E = 0$	-30
Emitter-Base Voltage	V_{EBO}	V	$I_E = -100\mu\text{A}$, $I_C = 0$	-5
Collector Current	I_C	A		-1
Collector Power Dissipation	P_C	mW		300
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	°C/W		417
Operation Junction Temperature	T_j	°C		150
Storage Temperature	T_{stg}	°C		-55 to +150

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
PBSS5130T	F2	Approximate 0.008	3000	30000	120000	7" reel

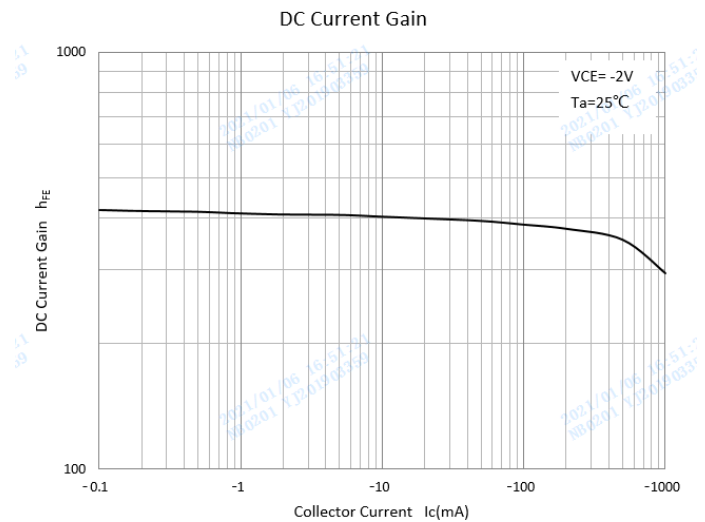
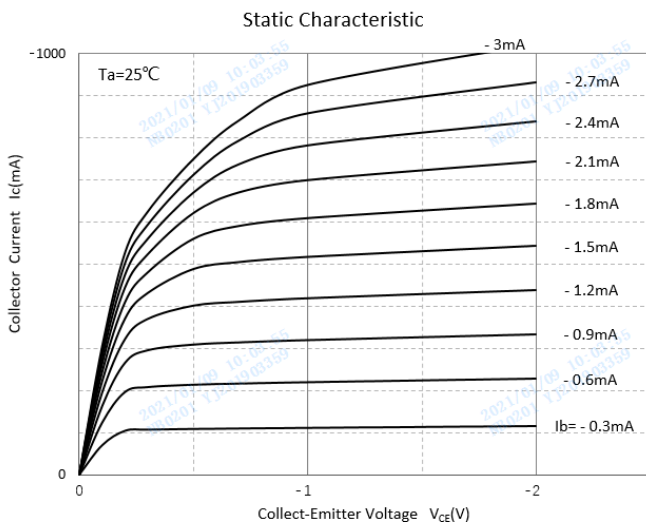


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■Electrical Characteristics (Ta=25°C)

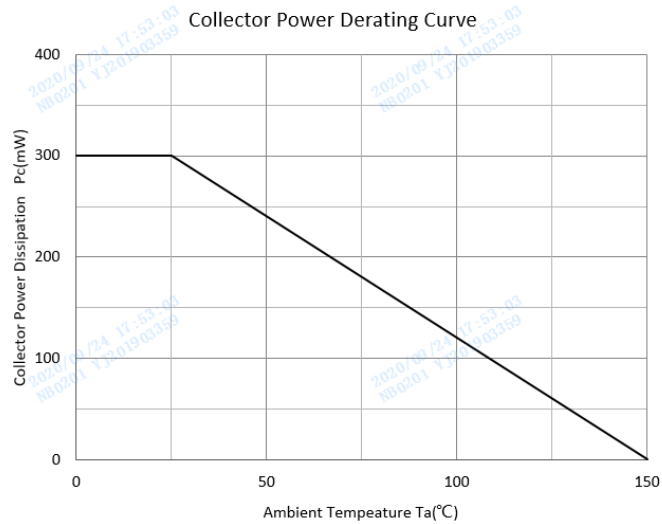
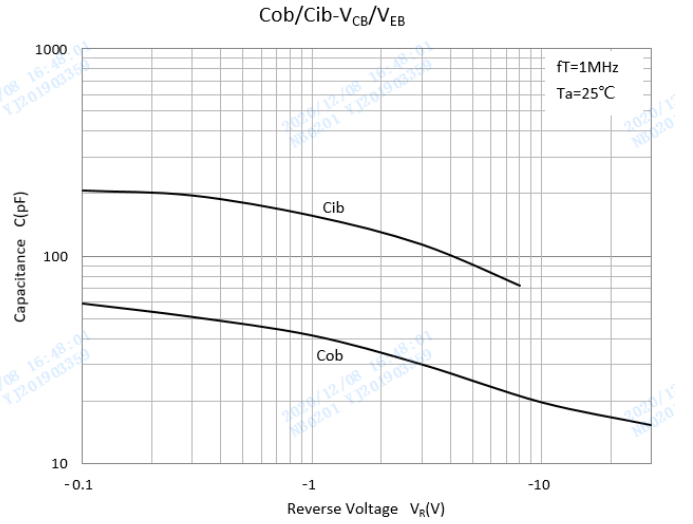
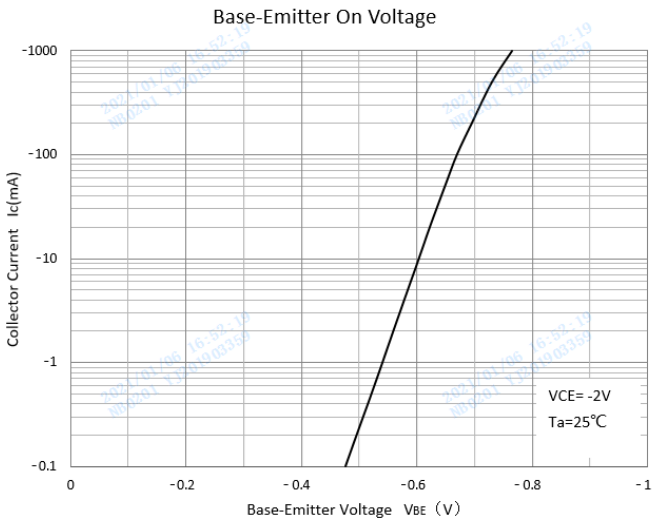
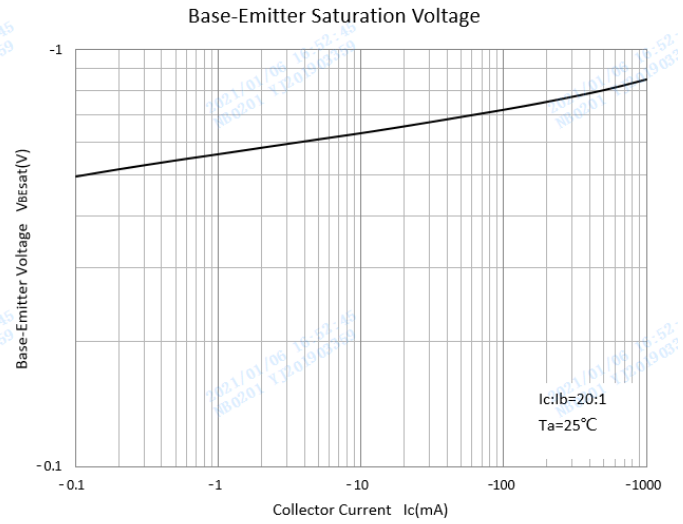
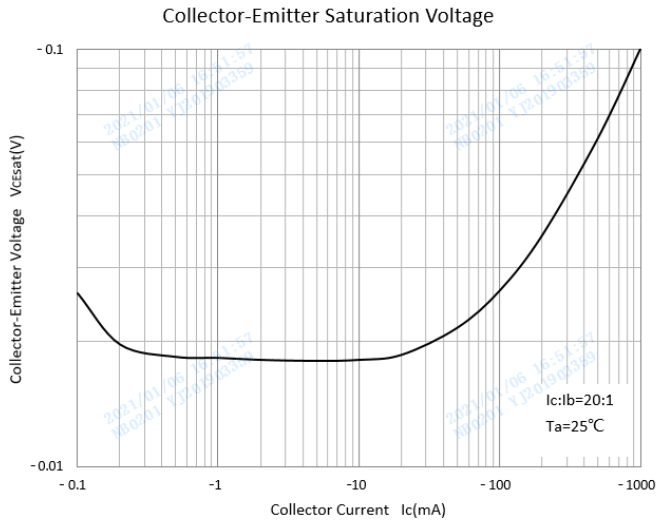
Item	Symbol	Unit	Conditions	Min	Max
Collector-Emitter Voltage	V_{CE0}	V	$I_C=-1mA, I_B=0$	-30	
Collector-Base Voltage	V_{CB0}	V	$I_C=-100\mu A, I_E=0$	-30	
Emitter-Base Voltage	V_{EB0}	V	$I_E=-100\mu A, I_C=0$	-5	
Collector-base Cut-off Current	I_{CBO}	nA	$V_{CB}=-30V$		-100
Base-emitter Cut-off Current	I_{EB0}	nA	$V_{EB}=-4V$		-100
DC Current Gain	h_{FE}		$I_C=-100mA, V_{CE}=-2V$	300	
			$I_C=-500mA, V_{CE}=-2V$	260	
			$I_C=-1A, V_{CE}=-2V$	210	
CollectorEmitter Saturation Voltage	$V_{CE(sat)1}$	mV	$I_C=-100mA, I_B=-1mA$		-100
	$V_{CE(sat)2}$	mV	$I_C=-1A, I_B=-50mA$		-225
Equivalent On-Resistance	$R_{CE(sat)}$	m Ω	$I_C=-500mA, I_B=-50mA$		220
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	V	$I_C=-1A, I_B=-100mA$		-1.1
Base-Emitter Turn-On Voltage	$V_{BE(on)}$	V	$I_C=-100mA, V_{CE}=-2V$		-0.75
Transition frequency	f_T	MHz	$I_C=-100mA, V_{CE}=-10V, f=100MHz$	100	
Collector Capacitance	C_{ob}	pF	$V_{CB}=-10V, I_E=0, f=1MHz$		28

■Characteristics(Typical)





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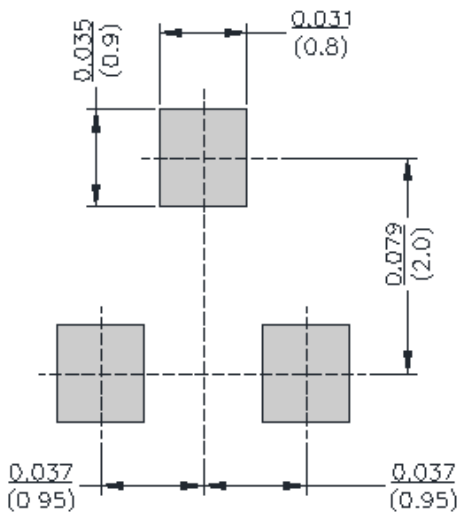
PBSS5130T

■SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

■SOT-23 Soldering Footprint





PBSS5130T

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